# NSN 5961-00-139-6626

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View Online at https://aerobasegroup.com/nsn/5961-00-139-6626

### Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

#### Terminal Length:

0.312 inches

#### **Overall Height:**

Between 0.250 inches and 0.450 inches

#### **Overall Width:**

1.050 inches

#### Mounting Facility Quantity:

2

Internal Configuration:

#### Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

## To-3

Electrode Internally-electrically Connected To Case:

#### Collector

**Mounting Method:** 

Unthreaded hole

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

350.0 breakdown voltage, collector-to-base, emitter open and 350.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current and 30.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

85.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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